## Amendments to the Specification

Please amend the title as follows

SEMICONDUCTOR DEVICE INCLUDING POWER MOSFET AND PERIPHERAL DEVICE

AND METHOD FOR MANUFACTURING THE SAME

Please amend the paragraph beginning at page 1, line 5, with the following rewritten paragraph:

This application is a divisional of Serial No. 09/804,024, which is based upon and claims the benefit of Japanese Patent Applications No. 2000-79344 filed on March 16, 2000, and No. 2000-79346 filed on March 16, 2000, the contents of which are incorporated herein by reference.